



Buy







CSD25304W1015

SLPS510A - JULY 2014-REVISED AUGUST 2014

# CSD25304W1015 20-V P-Channel NexFET™ Power MOSFET

#### Features 1

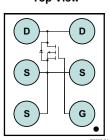
- Ultra-Low Q<sub>a</sub> and Q<sub>ad</sub>
- Small Footprint
- Low Profile 0.62 mm Height
- Pb Free
- **RoHS** Compliant
- Halogen Free
- CSP 1 x 1.5 mm Wafer Level Package •

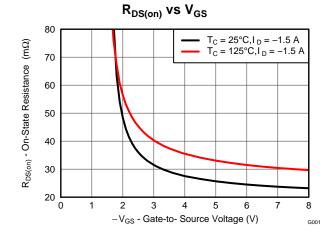
#### 2 Applications

- **Battery Management**
- Load Switch
- **Battery Protection** .

#### Description 3

This 27 m $\Omega$ , -20 V, P-Channel device is designed to deliver the lowest on-resistance and gate charge in a small 1.0 x 1.5 mm outline with excellent thermal characteristics in an ultra-low profile.





#### **Product Summary**

T <sub>A</sub> = 25°	c	TYPICAL VAL	UNIT						
V <sub>DS</sub>	Drain-to-Source Voltage –20								
Qg	Gate Charge Total (4.5 V)		nC						
Q <sub>gd</sub>	Gate Charge Gate-to-Drain 0.5								
		$V_{GS} = -1.8 V$	65	mΩ					
R <sub>DS(on)</sub>	Drain-to-Source On- Resistance	$V_{GS} = -2.5 V$	36	mΩ					
		$V_{GS} = -4.5 V$	27	mΩ					
V <sub>GS(th)</sub>	Voltage Threshold -0.8								

## Ordering Information<sup>(1)</sup>

Device	Qty	Media	Package	Ship
CSD25304W1015	3000	7-Inch Reel	1.0 mm × 1.5 mm	Tape and
CSD25304W1015T	250	7-Inch Reel	Wafer Level Package	Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

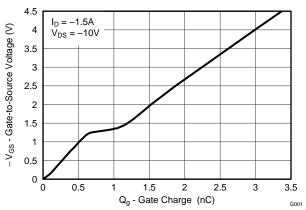
#### **Absolute Maximum Ratings**

		-	
T <sub>A</sub> = 2	5°C	VALUE	UNIT
$V_{\text{DS}}$	Drain-to-Source Voltage	-20	V
$V_{GS}$	Gate-to-Source Voltage	±8	V
ID	Continuous Drain Current <sup>(1)</sup>	-3.0	А
I <sub>DM</sub>	Pulsed Drain Current <sup>(2)</sup>	-41	А
PD	Power Dissipation	0.75	W
T <sub>J,</sub> T <sub>stg</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C

(1) Device operating at a temperature of 105°C

(2) Typ R<sub>θJA</sub> = 165°C/W, Pulse width ≤100 µs, duty cycle ≤1%

#### **Gate Charge**



**Top View** 

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#### Revision History 4

#### Changes from Original (July 2014) to Revision A Page Reduced power dissipation rating to 0.75 W (min Cu calculation) .....1

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## **5** Specifications

#### 5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS				ľ	
BV <sub>DSS</sub>	Drain-to-Source Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20			V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	$V_{GS} = 0 V, V_{DS} = -16 V$			-1	μA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			-100	nA
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.55	-0.8	-1.15	V
		$V_{GS} = -1.8 \text{ V}, \text{ I}_{D} = -1.5 \text{ A}$		65	92	mΩ
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -1.5 \text{ A}$		36	45.5	mΩ
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -1.5 \text{ A}$		27	32.5	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1.5 A		12		S
DYNAM	C CHARACTERISTICS				ļ	
C <sub>ISS</sub>	Input Capacitance			458	595	pF
C <sub>OSS</sub>	Output Capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = -10 V, <i>f</i> = 1 MHz		231	300	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance			12	15.6	pF
Qg	Gate Charge Total (-4.5 V)			3.3	4.4	nC
Q <sub>gd</sub>	Gate Charge Gate-to-Drain			0.5		nC
Q <sub>qs</sub>	Gate Charge Gate-to-Source	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1.5 \text{ A}$		0.7		nC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>			0.4		nC
Q <sub>OSS</sub>	Output Charge	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V		3.7		nC
t <sub>d(on)</sub>	Turn On Delay Time			6		ns
t <sub>r</sub>	Rise Time	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -1.5 \text{ A}$		4		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$R_{\rm G} = 20 \ \Omega$		24		ns
t <sub>f</sub>	Fall Time			10		ns
DIODE C	HARACTERISTICS		1		I	
V <sub>SD</sub>	Diode Forward Voltage	I <sub>S</sub> = –1.5 A, V <sub>GS</sub> = 0 V		-0.75	-1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DS</sub> = -10 V, I <sub>F</sub> = -1.5 A, di/dt = 200 A/µs		7.2		nC
t <sub>rr</sub>	Reverse Recovery Time	V <sub>DS</sub> = -10 V, I <sub>F</sub> = -1.5 A, di/dt = 200 A/µs		11.6		ns

#### 5.2 Thermal Information

( $T_A = 25^{\circ}C$  unless otherwise stated)

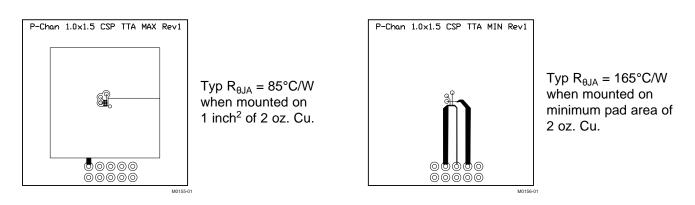
	THERMAL METRIC	MIN	TYP	MAX	UNIT
П	Junction-to-Ambient Thermal Resistance <sup>(1)</sup>		165		°C/W
R <sub>θJA</sub>	Junction-to-Ambient Thermal Resistance <sup>(2)</sup>		85		°C/W

Device mounted on FR4 material with minimum Cu mounting area.
Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.

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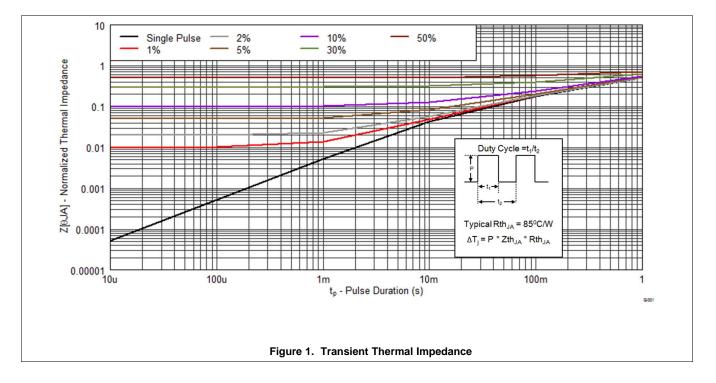


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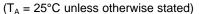
## 5.3 Typical MOSFET Characteristics

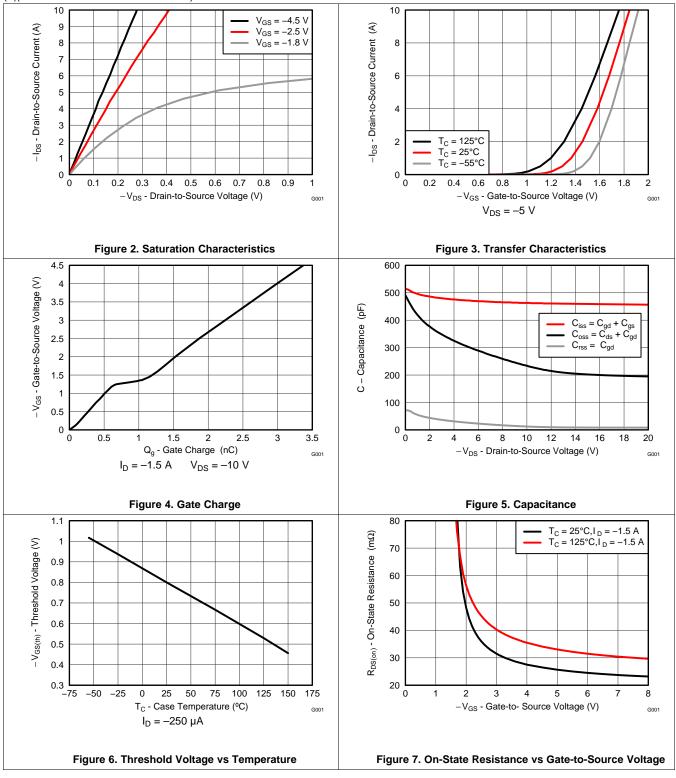
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 





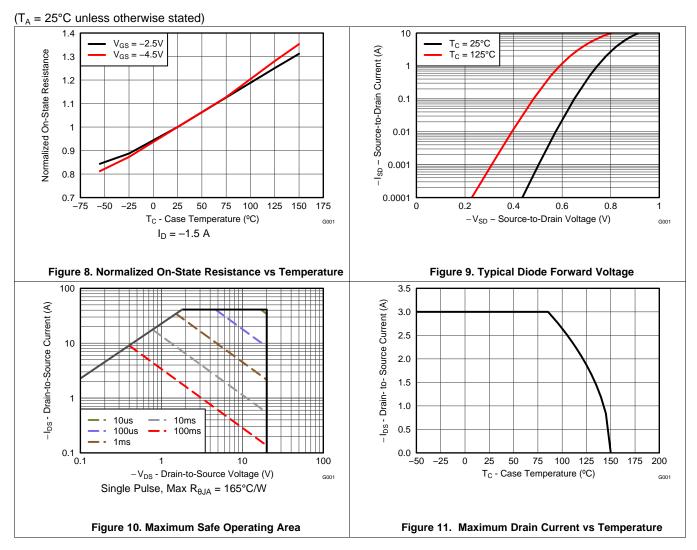
#### **Typical MOSFET Characteristics (continued)**







## **Typical MOSFET Characteristics (continued)**





## 6 Device and Documentation Support

#### 6.1 Trademarks

NexFET is a trademark of Texas Instruments.

#### 6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 6.3 Glossary

#### SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

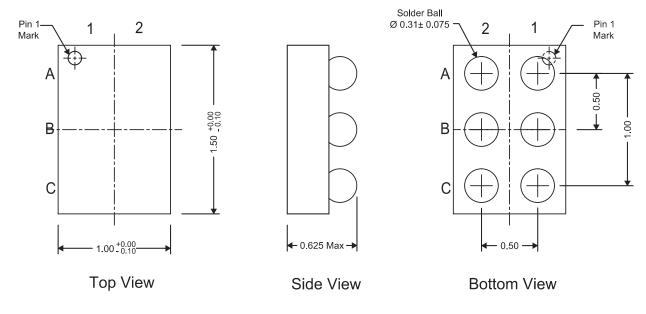
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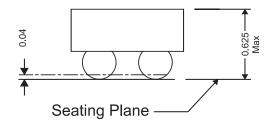
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## 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## 7.1 CSD25304W1015 Package Dimensions





## Front View

NOTE: All dimensions are in mm (unless otherwise specified).

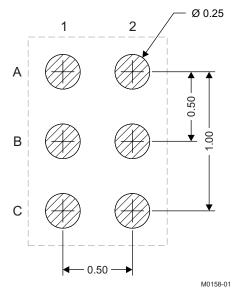
Pinout								
Designation								
Drain								
Gate								
Source								



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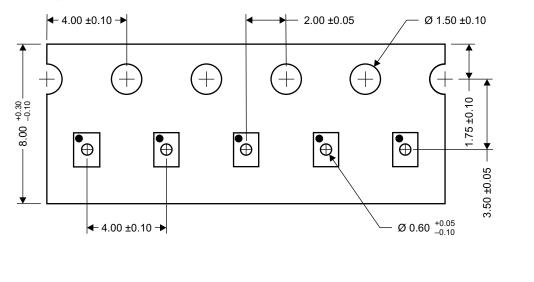


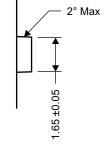
#### 7.2 Land Pattern Recommendation

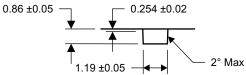


NOTE: All dimensions are in mm (unless otherwise specified).

#### 7.3 Tape and Reel Information







M0159-01

NOTE: All dimensions are in mm (unless otherwise specified).



1-Dec-2015

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD25304W1015	ACTIVE	DSBGA	YZC	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		25304	Samples
CSD25304W1015T	ACTIVE	DSBGA	YZC	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		25304	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE OPTION ADDENDUM

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